

THE BC413, BC414, BC415, BC416 ARE SILICON PLANAR EPITAXIAL TRANSISTORS FOR AF LOW NOISE PREAMPLIFIER APPLICATIONS. THE BC413, BC414 ARE NPN AND ARE COMPLEMENTARY TO THE PNP BC415, BC416 RESPECTIVELY.

CASE TO-92F



	BC413 (NPN)	BC414 (NPN)	BC415 (PNP)	BC416 (PNP)
Collector-Base Voltage	V _{CBO}	45V	50V	45V
Collector-Emitter Voltage	V _{CEO}	30V	45V	35V
Emitter-Base Voltage	V _{EBO}		5V	
Collector Current	I _C		100mA	
Total Power Dissipation @ T _A ≤25°C	P _{TOT}		300mW derate 2.4mW/°C above 25°C	
Operating Junction & Storage Temperature	T _j , T _{stg}		-55 to 150°C	

ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	TEST CONDITIONS
Collector-Base Breakdown Voltage BC413 BC414 BC415 BC416	BV _{CBO}	45 50 45 50			V	I _C =10µA I _E =0
Collector-Emitter Breakdown Voltage BC413 BC414 BC415 BC416	IV _{CEO}	30 45 35 45			V	I _C =10mA (Pulsed) I _B =0
Emitter-Base Breakdown Voltage	IV _{EBO}	5			V	I _E =10µA I _C =0
Collector Cutoff Current	I _{CBO}		15 5	nA µA		V _{CB} =30V I _E =0 V _{CB} =30V I _E =0 T _A =150°C
Emitter Cutoff Current	I _{EBO}		15	nA		V _{EB} =4V I _C =0
Collector-Emitter Saturation Voltage	V _{CE(sat)}	0.08 0.25 0.25 0.6	0.25 0.6	V	V	I _C =10mA I _B =0.5mA I _C =100mA I _B =5mA (Pulsed)

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PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	TEST CONDITIONS
Collector-Emitter Knee Voltage	V_{CEK}		0.3	0.6	V	$I_C=10mA$, I_B =value at which $I_C=11mA$ $V_{CE}=1V$
Base-Emitter Saturation Voltage	$V_{BE}(\text{sat})$		0.92		V	$I_C=100mA$ $I_B=5mA$ (Pulsed)
Base-Emitter Voltage	V_{BE}	0.55	0.64	0.75	V	$I_C=2mA$ $V_{CE}=5V$
			0.57		V	$I_C=0.1mA$ $V_{CE}=5V$
Current Gain-Bandwidth Product	f_T		200		MHz	$I_C=10mA$ $V_{CE}=5V$
Collector-Base Capacitance BC413, BC414 BC415, BC416	C_{CB}		2.7		pF	$V_{CB}=10V$ $I_E=0$
			3.2		pF	$f=1MHz$
Noise Figure BC413, BC414 BC415, BC416	NF		1.2	2.5	dB	$I_C=0.2mA$ $V_{CE}=5V$
			1.2	2.0	dB	$R_G=2K\Omega$ $f=30Hz-15KHz$
Flicker Noise Voltage Referred to Base BC413, BC414 BC415, BC416	$\overline{E_n}$			0.135	μV	$I_C=0.2mA$ $V_{CE}=5V$
				0.11	μV	$R_G=2K\Omega$ $f=10Hz-50Hz$

D.C. CURRENT GAIN (HFE) AT $V_{CE}=5V$ $T_A=25^\circ C$

@ I_C	HFE GROUP A			HFE GROUP B			HFE GROUP C		
	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX
0.01mA	40	100		100	170		100	290	
2mA	120	170	220	180	300	460	380	520	800
100mA	100			160			270		

h - PARAMETERS AT $I_C=2mA$ $V_{CE}=5V$ $f=1kHz$ $T_A=25^\circ C$

h - PARAMETER	SYMBOL	HFE GROUP A			HFE GROUP B			HFE GROUP C			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Input Impedance	h_{ie}	1.6	2.7	4.5	3.2	4.5	8.5	6	8.7	15	$K\Omega$
Voltage Feedback Ratio	h_{re}		1.5			2			3		$\times 10^{-4}$
Small Signal Current Gain	h_{fe}	125	190	260	240	330	500	450	580	900	
Output Admittance	h_{oe}		18	30		30	60		60	110	μV